

## High Energy Resolution Monochromated EELS-STEM System

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Exploring matter with a 10 meV-wide, atom-sized electron probe would allow us to perform many radically new electron energy loss spectroscopy (EELS) experiments, including investigations of atomic vibrations of very small amounts of matter, perhaps down to single atoms. The High Energy Resolution Monochromated EELS STEM (HERMES<sup>TM</sup>) system we have recently developed is now close to being able to reach such performance.

HERMES<sup>TM</sup> uses several new design principles [1-3]. The monochromation is carried out at the full primary energy rather than inside the electron gun, with an all-magnetic monochromator (MC) consisting of a main energy-dispersing prism, spectrum-magnifying quadrupoles, auxiliary prisms that bend the beam into an alpha-type trajectory, an adjustable energy-selecting slit equipped with intensity sensing, and aberration-correcting sextupoles and octupoles. The MC optics are dispersing-undispersing, and the energy dispersion of the beam is precisely cancelled at the MC exit. The main prism winding is connected in series with the prism of an all-magnetic EEL spectrometer, which means that the energy spectra produced in these two parts of the total system track each other, and small instabilities in the prism supply current do not change the position of the spectrum on the EELS detector. The high tension (HT) of the microscope is stabilized by sensing the electron current falling on the two halves of the MC slit in a feedback scheme that adjusts the HT such that the energy-dispersed beam remains precisely centered on the slit opening.

Our approach is more complicated than other MC designs – it is roughly equivalent to two parallel EELS systems running back-to-back. However, it provides several key advantages. First, because the beam traverses the MC at the full energy and the beam intensity is reduced by a pre-MC beam-defining aperture, Coulomb interactions between the beam electrons are greatly reduced, allowing high beam currents (e.g., 100 pA at 100 meV energy width) to be reached without broadening the beam unduly. Second, connecting the MC and EELS prisms in series, which is possible precisely because the MC operates on the full-energy beam, results in excellent short- and especially long-term energy stability. Third, full energy electrons are less sensitive to effects such as charging at the slit edges, and this allows the system to achieve very good spatial resolution while monochromating.

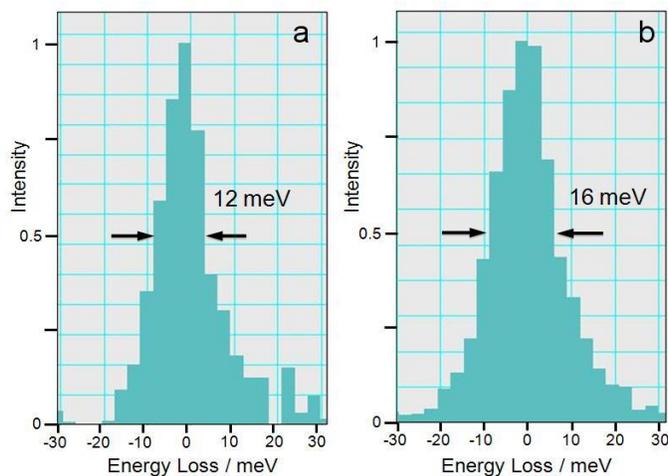
Other key components of the total system are an optimized cold field emission gun (CFEG), which provides a coherent current normalized by its energy spread [2] that is about 10x higher than possible with Schottky guns, an aberration corrector that achieves complete correction of geometric aberrations up to 5<sup>th</sup> order, and a total STEM system designed for the best stability possible with currently available technologies [4,5].

HERMES<sup>TM</sup> has been able to reach 12 meV full-width at half-maximum (FWHM) of the EELS zero loss peak (ZLP) in a short-exposure spectrum at a primary energy of 60 keV (Fig. 1), and an energy

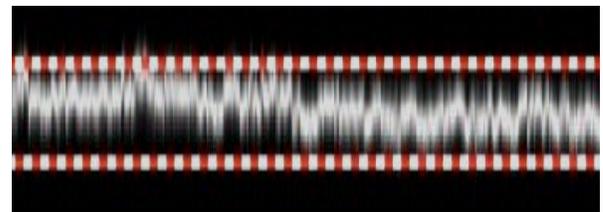
stability better than 20 meV r.m.s. over 100 seconds at 100 keV (Fig. 2). It is routinely able to operate with 30-40 meV energy resolution. When the energy-selecting slit is opened to admit an electron beam about 100 meV wide, the spatial resolution the system can reach is slightly improved compared to running with the MC turned off (and the beam going straight through it), or the MC on and the energy-selecting slit withdrawn from the beam [6]. Fig 3. shows EEL spectra of an SiO<sub>2</sub> layer in a MOSFET device acquired with about 40 meV energy resolution at 60 keV.

Further improvements in the energy resolution should be possible when the detector part of the column and the EELS (Gatan Enfium) are provided with similar stability measures as the probe-forming part of the column, which is able to keep the sample-level probe stable to around 0.1 Å r.m.s. [7]. We are now working in this direction, and we will report on our progress at the meeting.

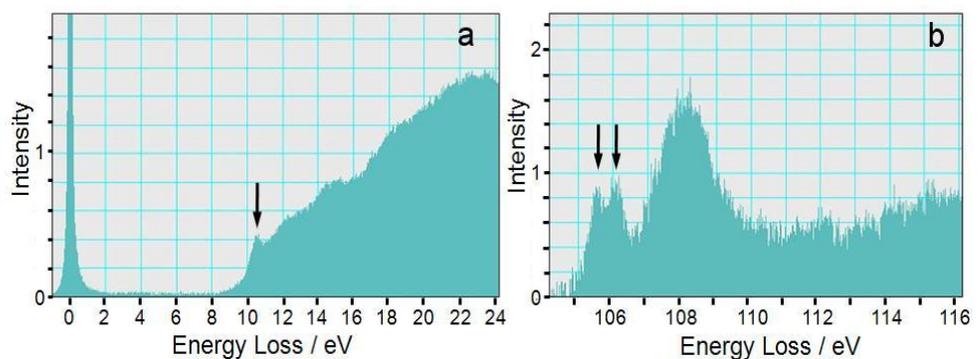
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 [2] O.L. Krivanek et al. (2013), *Microscopy*, in print (doi: 10.1093/jmicro/dfs089).  
 [3] O.L. Krivanek and N. Dellby (2013), US patent #8373137.  
 [4] O.L. Krivanek et al. (2008), *Ultramicroscopy* **108**, 179-195.  
 [5] N. Dellby et al. (2011), *EPJAP* **54**, 33505 (11 pages).  
 [6] T.C. Lovejoy et al. (2013), these proceedings.  
 [7] O.L. Krivanek et al. (2010), *Microscopy Microanalysis* **16** (Suppl. S2), 70–71.



**Fig. 1.** ZLPs acquired at 60 keV in a) 2 ms and b) 55 ms.



**Fig. 2.** The position of a 100 keV ZLP on the EELS detector as a function of time. Horizontal full width = 200 sec, striped reference lines are 80 meV apart.



**Fig. 3.** Si spectra from SiO<sub>2</sub> in a MOSFET integrated circuit. a) low loss spectrum acquired in 0.2 s, b) background-subtracted Si L<sub>2,3</sub> edge acquired in 50 s. The ZLP maximum intensity is 302. Band edge exciton is marked by an arrow in (a), 0.6 eV Si L<sub>3</sub>-L<sub>2</sub> threshold peak splitting is marked in (b).